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INFORMATION DISCLOSURE STATEMENT

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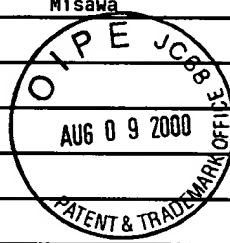
Applicant: Shunpei YAMAZAKI et al.

Filing Date: 11/23/98

Group: 2874

U.S. PATENT DOCUMENTS

Examiner Initial	Patent Number	Issue Date	Patentee	Class	Subclass	Filing Date (if approp.)
	5,250,931	10/05/93	Misawa			



FOREIGN PATENT DOCUMENTS

Document Number	Date	Country	Class	Subclass	Translation Yes No
*61-152069	07/10/86	Japan			Abst.
58-127318	02/07/84	Japan			Abst.
58-191420	10/20/83	Japan			Abst.

OTHER DOCUMENTS (Including Author, Title, Relevant Pages, Date, Place of Publication)

	*Merkle et al., "Picosecond Laser Pulse Irradiation of Crystalline Silicon," Appl. Phys. Lett., Vol. 40(8), 15 April 1982, pp. 729-731.
	*Jhee et al., "Charge Emission and Precursor Accumulation in the Multiple-Pulse Damage Regime of Silicon," J. Opt. Soc. Am. B, Vol. 2, No. 10, October 1985, pp. 1626-1633.
	*Liu et al., "Picosecond Laser-Induce Melting and Resolidification Morphology on Si", Appl. Phys. Lett. Vol. 34(12), 15 June 1979, pp. 864-866.

Examiner

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*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.